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CONFIRMATION NO. ATTORNEY DOCKET NO. FIRST NAMED INVENTOR FILING DATE APPLICATION NO. 9195 00 P 9119 US Jingyu Lian 09/751,551 12/28/2000 05/07/2003 EXAMINER SLATER & MATSIL, L.L.P. ORTIZ, EDGARDO 17950 PRESTON ROAD **SUITE 1000** DALLAS, TX 75252-5793 PAPER NUMBER ART UNIT 2815

Please find below and/or attached an Office communication concerning this application or proceeding.

Application No.
09/751,551

Applicant(s)

Examiner

Art Unit
Edgardo Ortiz 28

Lian Et.al.

Office Action Summary

	The MAILING DATE of this communication appears	on the cover sheet with the corres		
	for Reply			
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136 (a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the				
mailing - If the - If NO - Failure - Any re	go date of this communication. period for reply specified above is less than thirty (30) days, a reply within the period for reply is specified above, the maximum statutory period will apply to reply within the set or extended period for reply will, by statute, cause the period by the Office later than three months after the mailing date of a patent term adjustment. See 37 CFR 1.704(b).	the statutory minimum of thirty (30) days will b and will expire SIX (6) MONTHS from the maili the application to become ABANDONED (35 U.S	e considered timely, ng date of this communication. S.C. § 133).	
Status				
1) 💢	Responsive to communication(s) filed on Apr 2, 20	003		
2a) 🗌	This action is FINAL . 2b) 💢 This ac	tion is non-final.		
3) 🗌	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11; 453 O.G. 213.			
Disposi	tion of Claims			
4) 💢	Claim(s) 1-13, 21-29, and 31	is/are	e pending in the application.	
4	a) Of the above, claim(s)	is/ar	e withdrawn from consideration.	
5) 🗌	Claim(s)		is/are allowed.	
6) 💢	Claim(s) <u>1-13, 21-29, and 31</u>		is/are rejected.	
7) 🗆	Claim(s)		is/are objected to.	
8) 🗌	Claims	are subject to restric	ction and/or election requirement.	
Applica	tion Papers			
9) 🗌	The specification is objected to by the Examiner.			
10)	The drawing(s) filed on is/are a) accepted or b) objected to by the Examiner.			
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).			
11)	The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner			
	If approved, corrected drawings are required in reply to this Office action.			
12)	The oath or declaration is objected to by the Examiner.			
	under 35 U.S.C. §§ 119 and 120			
	Acknowledgement is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).			
a) L	a) □ All b) □ Some* c) □ None of:			
	1. Certified copies of the priority documents have been received.			
	2. Certified copies of the priority documents have been received in Application No			
	 Copies of the certified copies of the priority d application from the International Bure see the attached detailed Office action for a list of th 	eau (PCT Rule 17.2(a)).	this National Stage	
 14)				
15) 🗌	Acknowledgement is made of a claim for domestic) and/or 121	
Attachm		phoney under 33 0.3.C. 33 F20	Janu/or 121.	
_	errits) stice of References Cited (PTO-892)	4) Interview Summary (PTO-413) Paper	No(s).	
	rtice of Draftsperson's Patent Drawing Review (PTO-948)	5) Notice of Informal Patent Application		
3) X Inf	3) X Information Disclosure Statement(s) (PTO-1449) Paper No(s)			

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DETAILED ACTION

This Office Action is in response to a request for continued prosecution filed April 2, 2003 and wherein claims 1, 8 and 28 are amended.

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 2, 7, 8, 13 and 21-27 are rejected under 35 U.S.C. § 102 (b) as being anticipated by Nakabayashi (U.S. Patent No. 5,905,278). With regard to Claim 1, Nakabayashi teaches a conductive barrier layer (column 10, lines 38-49) and an electrode (25) comprising a first conductive liner (Ir) disposed over and electrically coupled to the conductive barrier layer, a second conductive liner (IrO2) disposed over the first conductive liner, the second conductive liner being electrically coupled to the first conductive liner and the conductive barrier layer and a conductive layer (Ir) disposed over the second conductive liner, the conductive layer being electrically coupled to the first conductive liner, the conductive barrier layer and the second conductive liner, wherein the conductive layer and the first conductive liner comprise the same material, see figure 8H.

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With regard to Claim 2, Nakabayashi teaches a second conductive liner (IrO2) of the lower

electrode (25) comprising a conductive oxide.

With regard to Claim 7, Nakabayashi teaches an integrated circuit comprising a FRAM (column 9,

lines 48-49).

With regard to Claim 8, Nakabayashi teaches a conductive barrier layer (column 10, lines 38-49)

and an electrode (25) comprising a first conductive liner (Ir) deposited over and abutting the

conductive barrier layer, the first conductive liner comprising a molecular grain structure having a

plurality of columns, a second conductive liner (IrO2) deposited over and abutting the first

conductive liner, the second conductive liner comprising a conductive oxide and a conductive

layer (Ir) disposed over and abutting the second conductive liner, the conductive layer comprising

a molecular grain structure having a plurality of columns, wherein the columns of the conductive

layer are not aligned with the columns of the first conductive liner, this is because of the presence

of the conductive oxide between first conductive liner and the conductive layer, see figure 8H.

With regard to Claim 13, Nakabayashi teaches an integrated circuit comprising a FRAM (column

9, lines 48-49).

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With regard to Claims 21 and 22, Nakabayashi teaches a second conductive liner comprising

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IrO2.

With regard to Claims 23 and 24, Nakabayashi teaches a conductive layer and a first conductive

liner comprising Ir.

With regard to Claims 25 and 27, the limitation "wherein the second conductive liner comprises a

thickness such that the second conductive liner is etchable by the same etchant used to etch the

first conductive liner and the conductive liner", is an intended use limitation that does not

distinguish the claimed invention from that taught by Nakabayashi. See In re Pearson 181 USPQ

641 (CCPA) which makes clear that terms merely setting forth intended use for, or a property

inherent in, an otherwise old composition do not differentiate claimed composition from those

known to prior art. See also, In re Swinehart [169 USPQ 226] (CCPA 1971) which makes clear

that mere recitation of a newly discovered function or property, inherently possessed by things in

prior art, does not cause claim drawn to those things to distinguish over prior art.

With regard to Claim 26, Nakabayashi teaches an electrode (25) having a conductive layer (Ir)

comprising a molecular grain structure having columns, the conductive layer including a top

surface, wherein the first conductive liner (Ir) comprises a molecular grain structure having

columns, wherein the columns of the conductive layer are not aligned with the columns of the first

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conductive liner, this is because of the presence of the conductive oxide (IrO2) between first conductive liner and the conductive layer.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 3, 5, 9 and 11 are rejected under 35 U.S.C. § 103 (a) as being unpatentable over Nakabayashi (U.S. Patent No. 5,905,278). Nakabayashi, as stated supra, essentially discloses the claimed invention but fails to show, the thicknesses of the first and second conductive liners. With regard to claims 3, 5, 9 and 11, it would have been an obvious modification to someone with ordinary skill in the art, at the time of the invention, to modify the structure as taught by Nakabayashi to include the thickness of the first and second conductive liners as claimed, in order to reduce oxygen diffusion into a conductive layer such as polysilicon below the multi-layer electrode.

Claims 4, 10, 28, 29 and 31 are rejected under 35 U.S.C. § 103 (a) as being unpatentable over Nakabayashi (U.S. Patent No. 5,905,278) in view of Ramesh (U.S. Patent No. 5,838, 035). With

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regard to Claims 4, 10 and 28, Nakabayashi essentially discloses the claimed invention but fails to

show, that the conductive layer and the first conductive liner comprise platinum. Ramesh discloses

a capacitor stack with a multi-layer electrode including a barrier layer (72) over a conductive plug

(42) of polysilicon, a first conductive layer (74) comprising platinum and a second conductive

layer (78) also comprising platinum, see figure 4. Therefore, it would have been an obvious

modification to someone with ordinary skill in the art, at the time of the invention, to modify the

structure as taught by Nakabayashi to include a conductive layer and a first conductive liner

wherein both comprise platinum, as clearly suggested by Ramesh, in order to provide an electrode

structure which makes use of conductive layers with materials from the precious metals group,

which includes both platinum and iridium, known for their conductivity.

With regard to Claim 29, Nakabayashi teaches a second conductive liner comprising IrO2.

With regard to Claim 31, a further difference between the claimed invention and Nakabayashi and

Ramesh is, a thickness of the conductive oxide. It would have been an obvious modification to

someone with ordinary skill in the art, at the time of the invention, to modify the structure as

taught by Nakabayashi and Ramesh to include a thickness of the conductive oxide as claimed, in

order to reduce oxygen diffusion into a conductive layer such as polysilicon below the multi-layer

electrode.

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Claims 6 and 12 are rejected under 35 U.S.C. § 103 (a) as being unpatentable over Nakabayashi (U.S. Patent No. 5,905,278) in view of Yokoyama et.al. (U.S. Patent No. 6,313,539). With regard to Claims 6 and 12, Nakabayashi essentially discloses the claimed invention but fails to show, a barrier layer comprising TaSiN. Yokoyama discloses a semiconductor memory device including a barrier layer (516) comprising TaSiN, see figure 22C. Therefore, it would have been an obvious modification to someone with ordinary skill in the art, at the time of the invention, to modify the structure as taught by Nakabayashi to include a barrier layer comprising TaSiN, as clearly suggested by Yokoyama, in order to provide barrier layer comprising a material known for its anti-heat and anti-oxidation properties.

Response to Arguments

3. Applicant's arguments with respect to claims 1-13, 21-29 and 31 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Examiner Edgardo Ortiz (Art Unit 2815), whose telephone number is (703) 308-6183 or by fax at (703) 308-7722. In case the Examiner can not be reached by a direct telephone call, you might call Supervisor Eddie Lee at (703) 308-1690. Any inquiry of a general

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nature or relating to the status of this application should be directed to the Group 2800 receptionist whose telephone number is (703) 308-0956.

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